



BC846AW - BC848CW

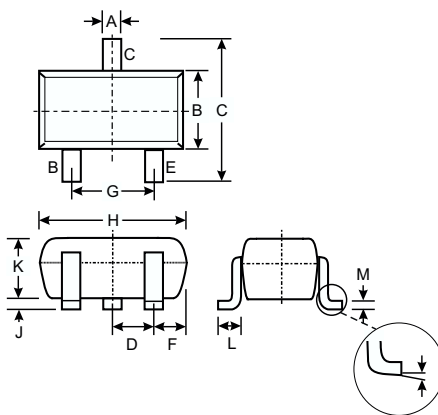
NPN SURFACE MOUNT SMALL SIGNAL TRANSISTOR

Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types Available (BC856W-BC858W)
- For Switching and AF Amplifier Applications

Mechanical Data

- Case: SOT-323, Molded Plastic
- Case material - UL Flammability Rating Classification 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Pin Connections: See Diagram
- Marking Codes (See Table Below & Diagram on Page 2)
- Ordering & Date Code Information: See Page 2
- Approx. Weight: 0.006 grams



SOT-323		
Dim	Min	Max
A	0.25	0.40
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.18
α	0°	8°
All Dimensions in mm		

Marking Code (Note 2)			
Type	Marking	Type	Marking
BC846AW	K1Q	BC847CW	K1M
BC846BW	K1R	BC848AW	K1J, K1E, K1Q
BC847AW	K1E, K1Q	BC848BW	K1K, K1F, K1R
BC847BW	K1F, K1R	BC848CW	K1L, K1M

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	80	V
		50	
		30	
Collector-Emitter Voltage	V_{CEO}	65	V
		45	
		30	
Emitter-Base Voltage	V_{EBO}	6.0 5.0	V
Collector Current	I_C	100	mA
Peak Collector Current	I_{CM}	200	mA
Peak Emitter Current	I_{EM}	200	mA
Power Dissipation (Note 1)	P_d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	$^\circ\text{C}$

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. Current gain subgroup "C" is not available for BC846W.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage (Note 3)	BC846 BC847 BC848 $V_{(BR)CBO}$	80 50 30	— — —	— — —	V	$I_C = 10\mu\text{A}$, $I_B = 0$
Collector-Emitter Breakdown Voltage (Note 3)	BC846 BC847 BC848 $V_{(BR)CEO}$	65 45 30	— — —	— — —	V	$I_C = 10\text{mA}$, $I_B = 0$
Emitter-Base Breakdown Voltage (Note 3)	BC846, BC847 BC848 $V_{(BR)EBO}$	6 5	—	—	V	$I_E = 1\mu\text{A}$, $I_C = 0$
DC Current Gain Current Gain Group A B C (Note 3)	h_{FE}	110 200 420	180 290 520	220 450 800	—	$V_{CE} = 5.0\text{V}$, $I_C = 2.0\text{mA}$
Collector-Emitter Saturation Voltage (Note 3)	$V_{CE(SAT)}$	—	90 200	250 600	mV	$I_C = 10\text{mA}$, $I_B = 0.5\text{mA}$ $I_C = 100\text{mA}$, $I_B = 5.0\text{mA}$
Base-Emitter Saturation Voltage (Note 3)	$V_{BE(SAT)}$	—	700 900	—	mV	$I_C = 10\text{mA}$, $I_B = 0.5\text{mA}$ $I_C = 100\text{mA}$, $I_B = 5.0\text{mA}$
Base-Emitter Voltage (Note 3)	$V_{BE(ON)}$	580 —	660 —	700 770	mV	$V_{CE} = 5.0\text{V}$, $I_C = 2.0\text{mA}$ $V_{CE} = 5.0\text{V}$, $I_C = 10\text{mA}$
Collector-Cutoff Current (Note 3)	I_{CBO} I_{CBO}	— —	— —	15 5.0	nA μA	$V_{CB} = 30\text{V}$ $V_{CB} = 30\text{V}$, $T_A = 150^\circ\text{C}$
Gain Bandwidth Product	f_T	100	300	—	MHz	$V_{CE} = 5.0\text{V}$, $I_C = 10\text{mA}$, $f = 100\text{MHz}$
Collector-Base Capacitance	C_{CBO}	—	3.0	4.5	pF	$V_{CB} = 10\text{V}$, $f = 1.0\text{MHz}$
Noise Figure	NF	—	—	10	dB	$V_{CE} = 5\text{V}$, $I_C = 200\mu\text{A}$, $R_S = 2.0\text{k}\Omega$, $f = 1.0\text{kHz}$, $\Delta f = 200\text{Hz}$

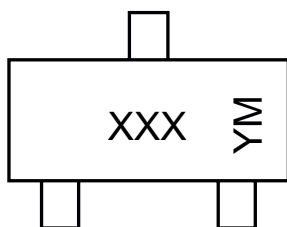
Ordering Information (Note 4)

Device	Packaging	Shipping
BC84xxW-7*	SOT-323	3000/Tape & Reel

Notes: 3. Short duration pulse test to minimize self-heating effect.

4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

*xx = device type, e.g. BC846AW-7.

Marking Information

XXX = Product Type Marking Code (See Page 1), e.g. K1Q = BC846AW

YM = Date Code Marking

Y = Year ex: N = 2002

M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004
Code	J	K	L	M	N	P	R

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D